

### Features

- Designed for soft commutation only
- Maximum junction temperature:  $T_J = 175\text{ }^\circ\text{C}$
- Minimized tail current
- $V_{CE(sat)} = 2.0\text{ V (typ.) @ } I_C = 15\text{ A}$
- Tight parameters distribution
- Safe paralleling
- Very low  $V_F$  soft recovery co-packaged diode
- Low thermal resistance
- Lead free package

### Applications

- Induction heating
- Microwave oven
- Resonant converters

### Description

These IGBTs are developed using an advanced proprietary trench gate field-stop structure and performance is optimized in both conduction and switching losses. A freewheeling diode with a low drop forward voltage is co-packaged. The result is a product specifically designed to maximize efficiency for any resonant and soft-switching application.

Figure 1. Internal schematic diagram

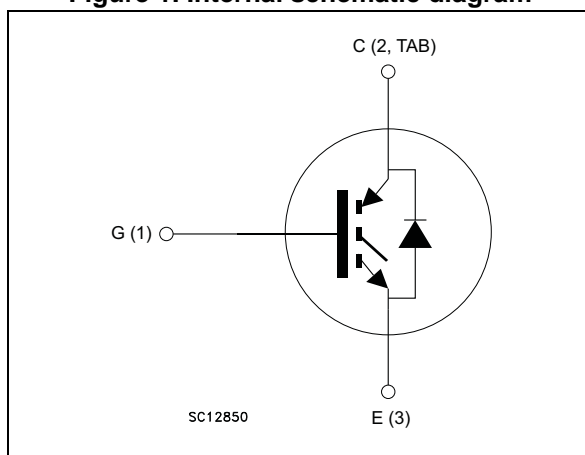


Table 1. Device summary

| Order code     | Marking    | Package | Packaging |
|----------------|------------|---------|-----------|
| STGW20IH125DF  | G20IH125DF | TO-247  | Tube      |
| STGWT20IH125DF | G20IH125DF | TO-3P   | Tube      |

# Contents

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# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

| Symbol         | Parameter   | Value       | Unit               |
|----------------|---|-------------|--------------------|
| $V_{CES}$      | Collector-emitter voltage ( $V_{GE} = 0$ )            | 1250        | V                  |
| $I_C$          | Continuous collector current at $T_C = 25\text{ °C}$  | 40          | A                  |
| $I_C$          | Continuous collector current at $T_C = 100\text{ °C}$ | 20          | A                  |
| $I_{CP}^{(1)}$ | Pulsed collector current                              | 80          | A                  |
| $V_{GE}$       | Gate-emitter voltage                                  | $\pm 20$    | V                  |
| $I_F$          | Continuous forward current at $T_C = 25\text{ °C}$    | 40          | A                  |
| $I_F$          | Continuous forward current at $T_C = 100\text{ °C}$   | 20          | A                  |
| $I_{FP}^{(1)}$ | Pulsed forward current                                | 80          | A                  |
| $P_{TOT}$      | Total dissipation at $T_C = 25\text{ °C}$             | 259         | W                  |
| $T_{STG}$      | Storage temperature range                             | - 55 to 150 | $^{\circ}\text{C}$ |
| $T_J$          | Operating junction temperature                        | - 55 to 175 | $^{\circ}\text{C}$ |

1. Pulse width limited by maximum junction temperature

**Table 3. Thermal data**

| Symbol     | Parameter                              | Value | Unit                        |
|------------|--|-------|-----------------------------|
| $R_{thJC}$ | Thermal resistance junction-case IGBT  | 0.58  | $^{\circ}\text{C}/\text{W}$ |
| $R_{thJC}$ | Thermal resistance junction-case diode | 1.47  | $^{\circ}\text{C}/\text{W}$ |
| $R_{thJA}$ | Thermal resistance junction-ambient    | 50    | $^{\circ}\text{C}/\text{W}$ |

## 2 Electrical characteristics

$T_J = 25\text{ °C}$  unless otherwise specified.

**Table 4. Static characteristics**

| Symbol        | Parameter  | Test conditions  | Min. | Typ. | Max. | Unit          |
|---------------|--|--|------|------|------|---------------|
| $V_{(BR)CES}$ | Collector-emitter breakdown voltage ( $V_{GE} = 0$ ) | $I_C = 2\text{ mA}$  | 1250 |      |      | V             |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage                 | $V_{GE} = 15\text{ V}, I_C = 15\text{ A}$                          |      | 2    | 2.5  | V             |
|               |  | $V_{GE} = 15\text{ V}, I_C = 15\text{ A}$<br>$T_J = 125\text{ °C}$ |      | 2.2  |      |               |
|               |  | $V_{GE} = 15\text{ V}, I_C = 15\text{ A}$<br>$T_J = 175\text{ °C}$ |      | 2.3  |      |               |
|               |  | $V_{GE} = 15\text{ V}, I_C = 30\text{ A}$                          |      | 2.55 |      |               |
| $V_F$         | Forward on-voltage                                   | $I_F = 15\text{ A}$  |      | 1.1  | 1.5  | V             |
|               |  | $I_F = 15\text{ A } T_J = 125\text{ °C}$                           |      | 1.05 |      |               |
|               |  | $I_F = 15\text{ A } T_J = 175\text{ °C}$                           |      | 1    |      |               |
|               |  | $I_F = 30\text{ A}$  |      | 1.25 |      |               |
| $V_{GE(th)}$  | Gate threshold voltage                               | $V_{CE} = V_{GE}, I_C = 500\text{ }\mu\text{A}$                    | 5    | 6    | 7    | V             |
| $I_{CES}$     | Collector cut-off current ( $V_{GE} = 0$ )           | $V_{CE} = 1250\text{ V}$   |      |      | 25   | $\mu\text{A}$ |
| $I_{GES}$     | Gate-emitter leakage current ( $V_{CE} = 0$ )        | $V_{GE} = \pm 20\text{ V}$   |      |      | 250  | nA            |

**Table 5. Dynamic characteristics**

| Symbol    | Parameter                    | Test conditions  | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|--|------|------|------|------|
| $C_{ies}$ | Input capacitance            | $V_{CE} = 25\text{ V}, f = 1\text{ MHz},$<br>$V_{GE} = 0$  | -    | 1290 | -    | pF   |
| $C_{oes}$ | Output capacitance           |  | -    | 96   | -    | pF   |
| $C_{res}$ | Reverse transfer capacitance |  | -    | 30.6 | -    | pF   |
| $Q_g$     | Total gate charge            | $V_{CC} = 600\text{ V}, I_C = 15\text{ A},$<br>$V_{GE} = 15\text{ V},$ see <a href="#">Figure 25</a> | -    | 69   | -    | nC   |
| $Q_{ge}$  | Gate-emitter charge          |  | -    | 7.2  | -    | nC   |
| $Q_{gc}$  | Gate-collector charge        |  | -    | 40.8 | -    | nC   |

Table 6. IGBT switching characteristics (inductive load)

| Symbol          | Parameter                 | Test conditions   | Min. | Typ. | Max. | Unit          |
|-----------------|---------------------------|---|------|------|------|---------------|
| $t_{d(off)}$    | Turn-off delay time       | $V_{CE} = 600\text{ V}$ , $I_C = 15\text{ A}$ ,<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ , see<br><a href="#">Figure 23</a>                                     |      | 106  |      | ns            |
| $t_f$           | Current fall time         |   | -    | 79   | -    | ns            |
| $E_{off}^{(1)}$ | Turn-off switching losses |   | -    | 410  | -    | $\mu\text{J}$ |
| $t_{d(off)}$    | Turn-off delay time       | $V_{CE} = 600\text{ V}$ , $I_C = 15\text{ A}$ ,<br>$R_G = 10\ \Omega$ , $V_{GE} = 15\text{ V}$ ,<br>$T_J = 175\text{ }^\circ\text{C}$ , see <a href="#">Figure 23</a> |      | 109  |      | ns            |
| $t_f$           | Current fall time         |   | -    | 176  | -    | ns            |
| $E_{off}^{(1)}$ | Turn-off switching losses |   | -    | 820  | -    | $\mu\text{J}$ |

1. Turn-off losses include also the tail of the collector current.

Table 7. IGBT switching characteristics (capacitive load)

| Symbol          | Parameter                 | Test conditions   | Min. | Typ. | Max. | Unit          |
|-----------------|---------------------------|---|------|------|------|---------------|
| $E_{off}^{(1)}$ | Turn-off switching losses | $V_{CC} = 900\text{ V}$ , $R_G = 10\ \Omega$ ,<br>$I_C = 30\text{ A}$ , $L = 500\ \mu\text{H}$ ,<br>$C_{snub} = 330\text{ nF}$ , see<br><a href="#">Figure 24</a>                                     | -    | 163  | -    | $\mu\text{J}$ |
|                 |                           | $V_{CC} = 900\text{ V}$ , $R_G = 10\ \Omega$ ,<br>$I_C = 30\text{ A}$ , $L = 500\ \mu\text{H}$ ,<br>$C_{snub} = 330\text{ nF}$ , $T_J = 175\text{ }^\circ\text{C}$ ,<br>see <a href="#">Figure 24</a> | -    | 366  | -    |               |

1. Turn-off losses include also the tail of the collector current.

## 2.1 Electrical characteristics (curves)

Figure 2. Power dissipation vs. case temperature

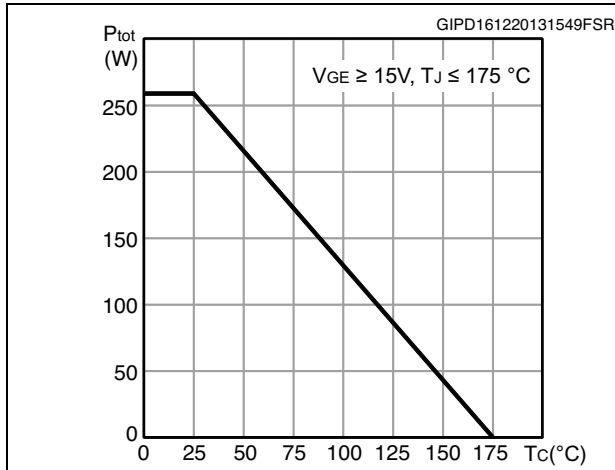


Figure 3. Collector current vs. case temperature

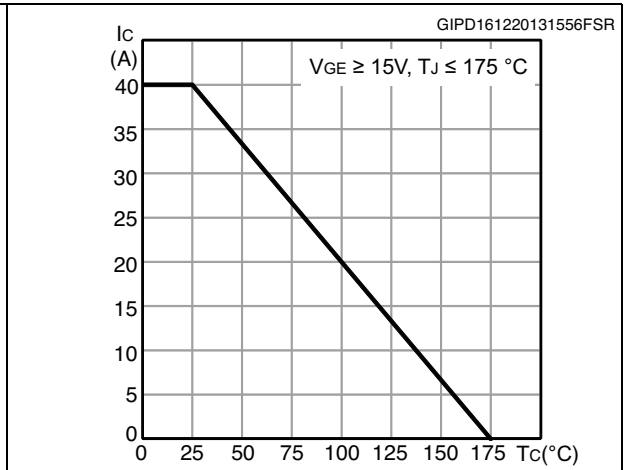


Figure 4. Output characteristics (T<sub>J</sub> = 25°C)

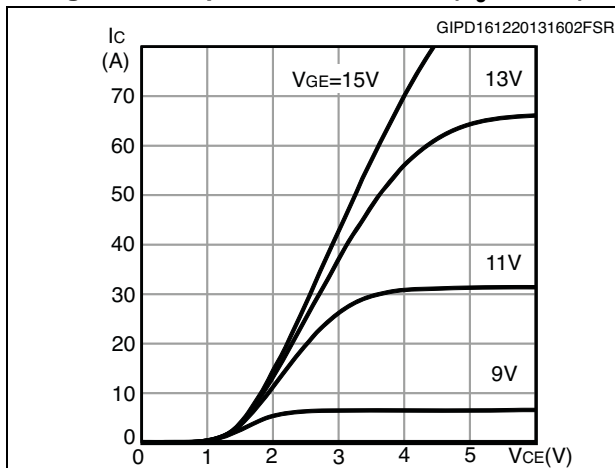


Figure 5. Output characteristics (T<sub>J</sub> = 175°C)

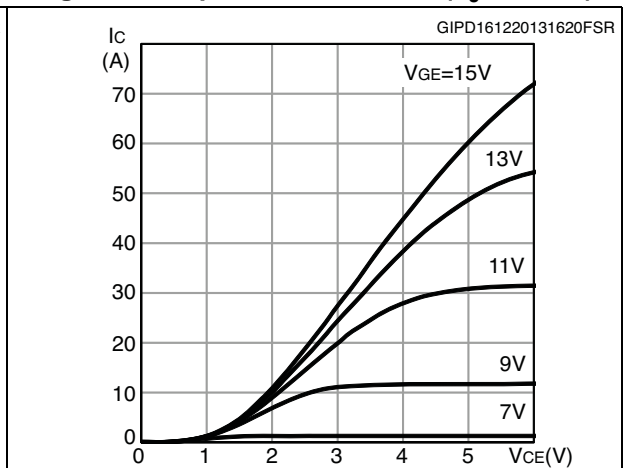


Figure 6. V<sub>CE(sat)</sub> vs. junction temperature

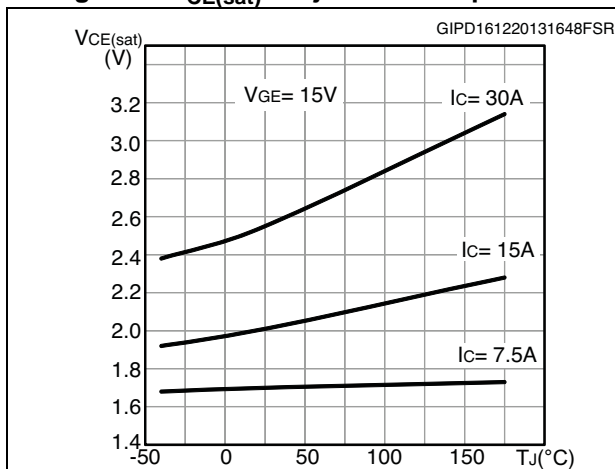


Figure 7. V<sub>CE(sat)</sub> vs. collector current

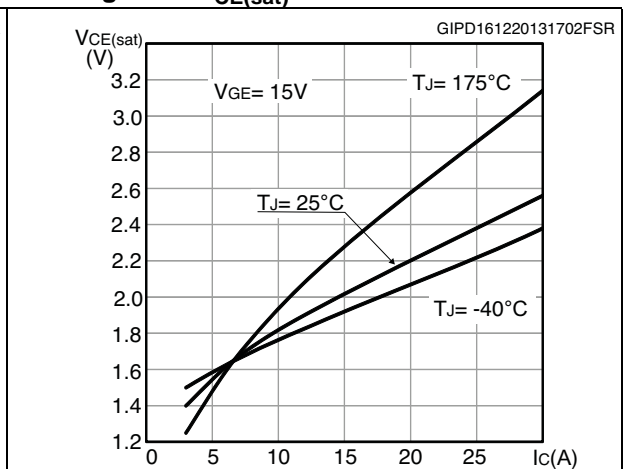


Figure 8. Forward bias safe operating area

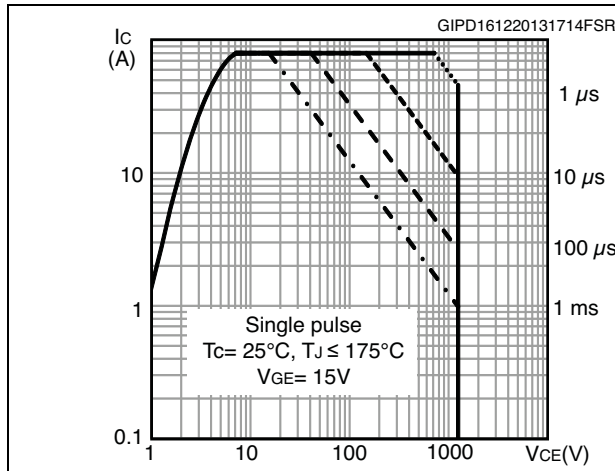


Figure 9. Transfer characteristics

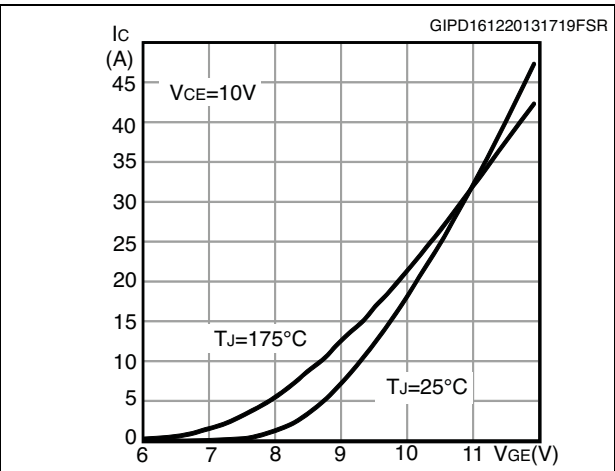


Figure 10. Diode V\_F vs. forward current

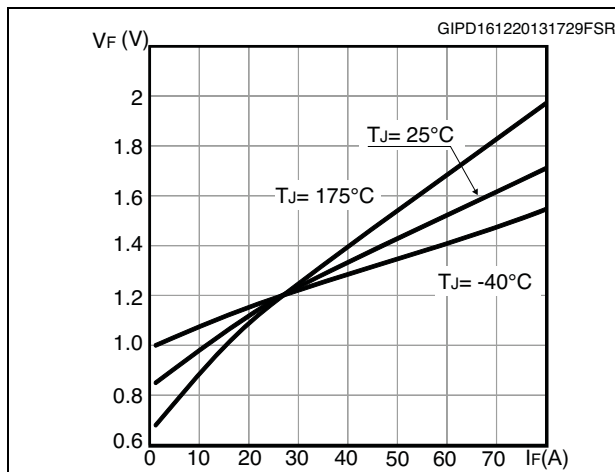


Figure 11. Normalized V\_GE(th) vs junction temperature

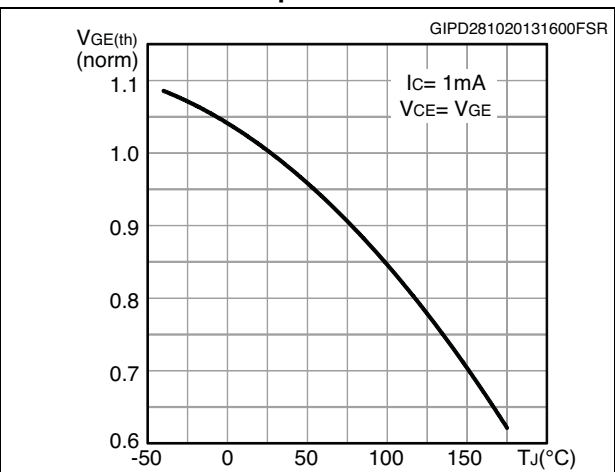


Figure 12. Normalized V\_(BR)CES vs. junction temperature

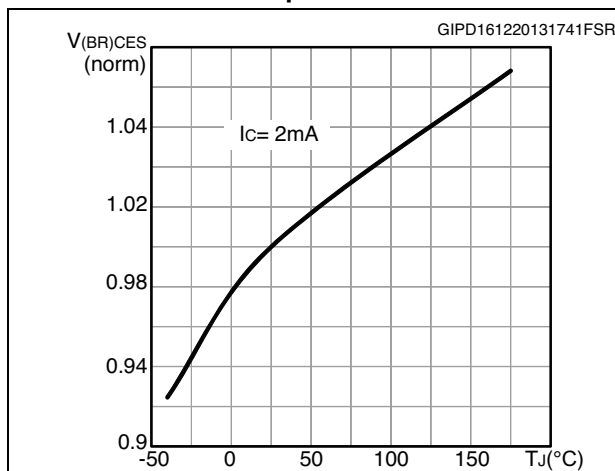


Figure 13. Capacitance variation

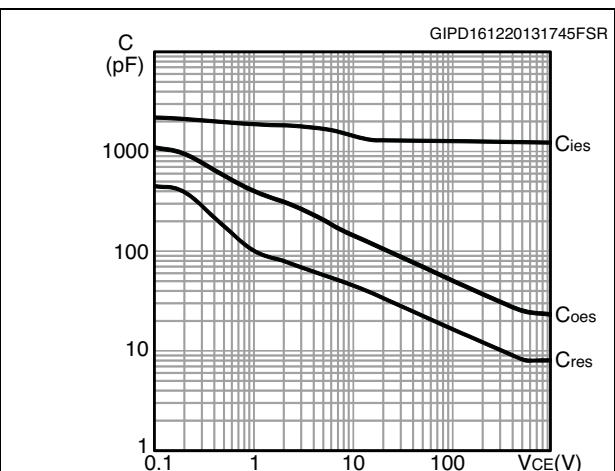


Figure 14. Gate charge vs. gate-emitter voltage

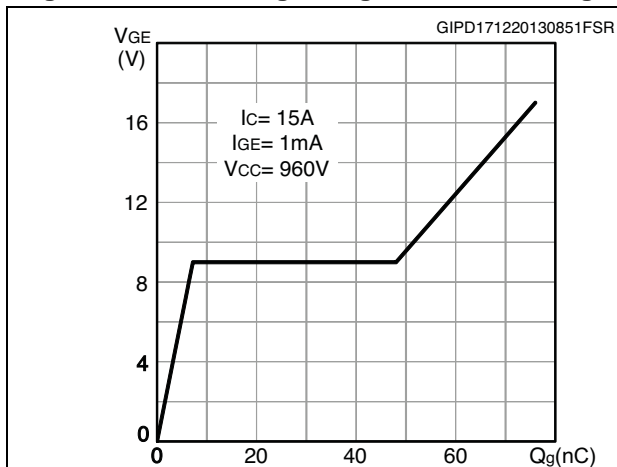


Figure 15. Switching loss vs collector current

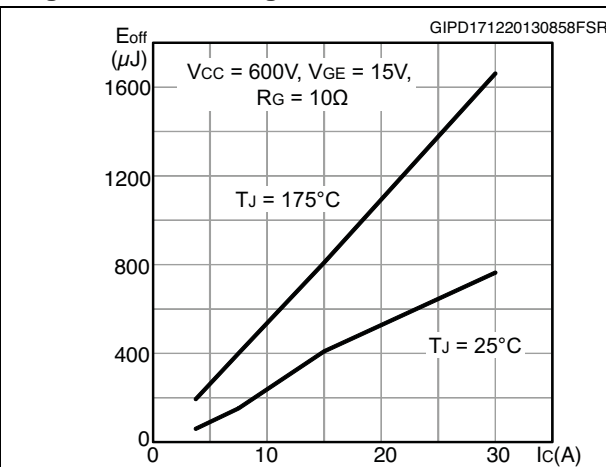


Figure 16. Switching-off loss vs gate resistance

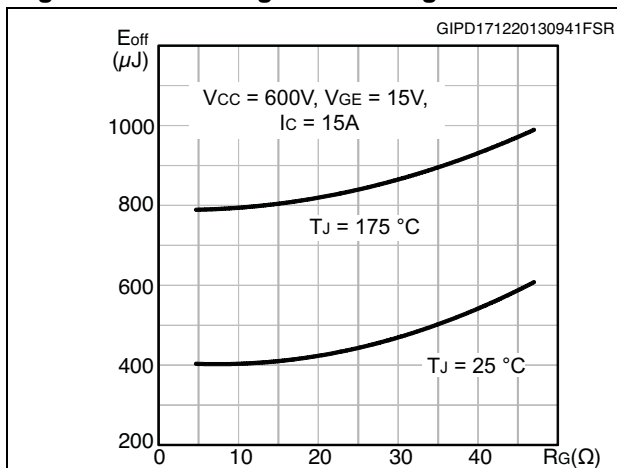


Figure 17. Switching-off loss vs temperature

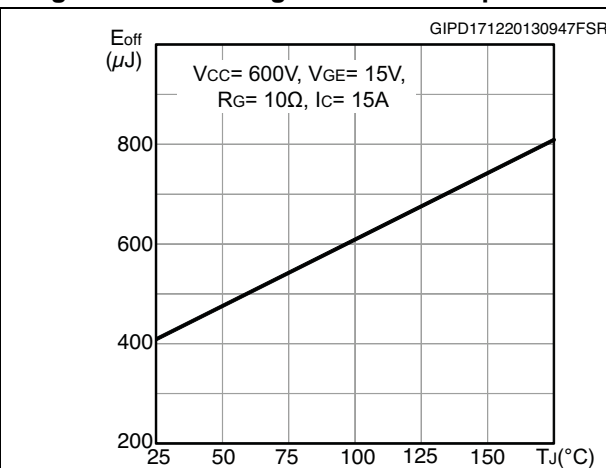


Figure 18. Switching-off loss vs collector-emitter voltage

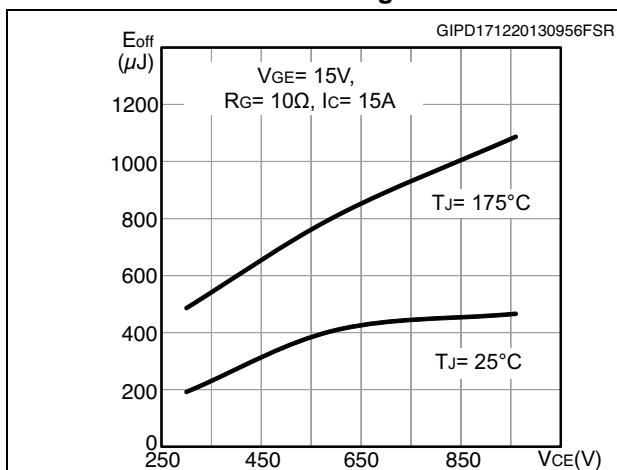


Figure 19. Switching times vs. collector current

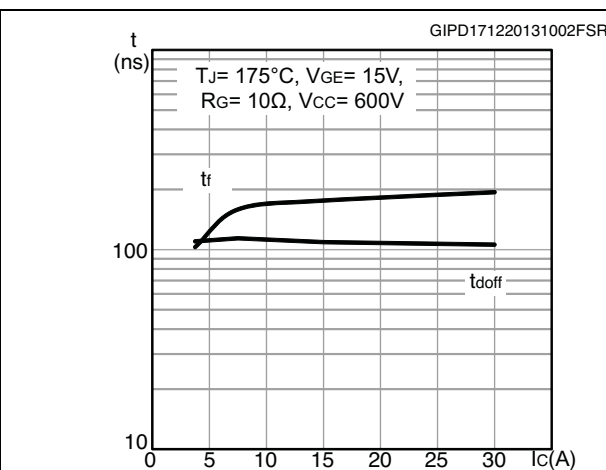




Figure 20. Switching times vs. gate resistance

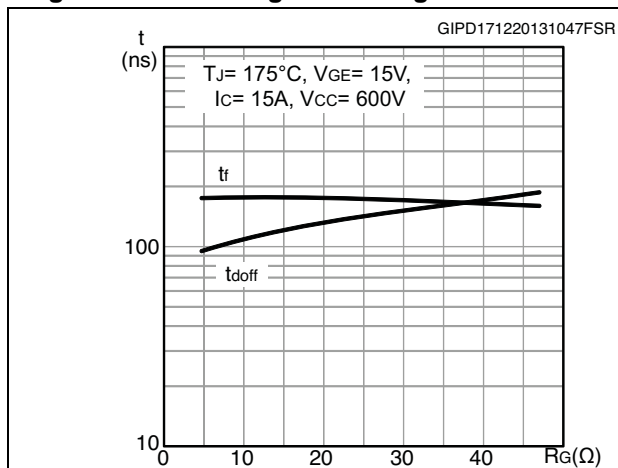


Figure 21. Thermal impedance for IGBT

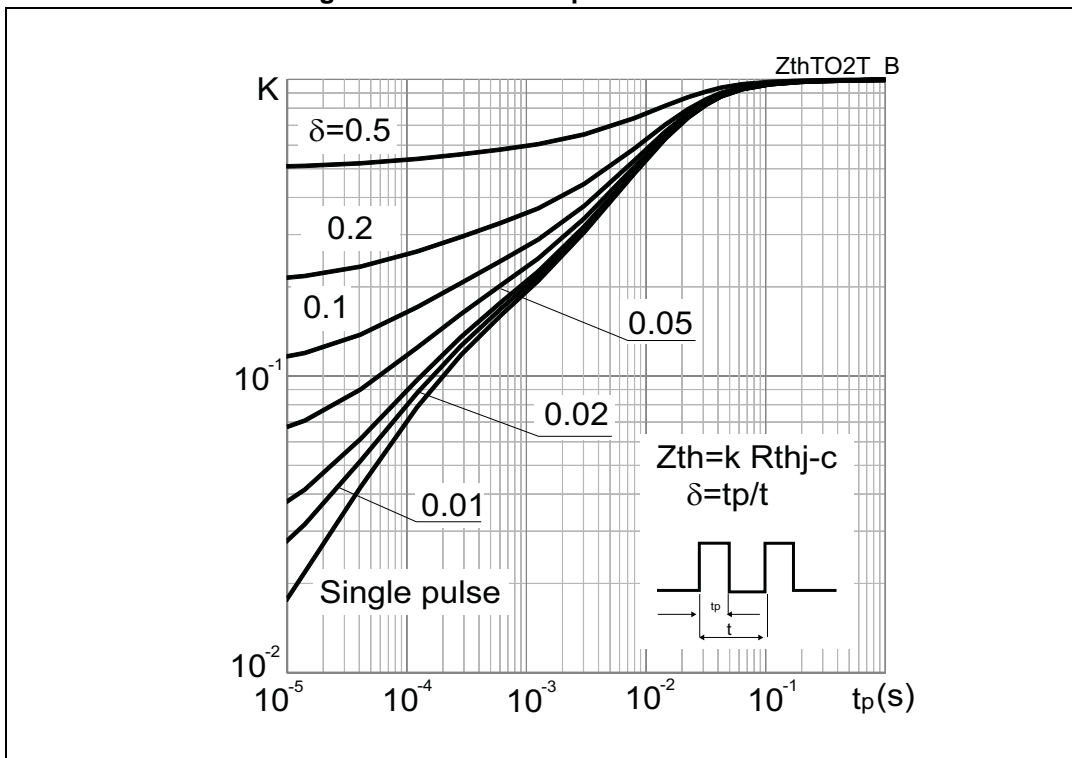
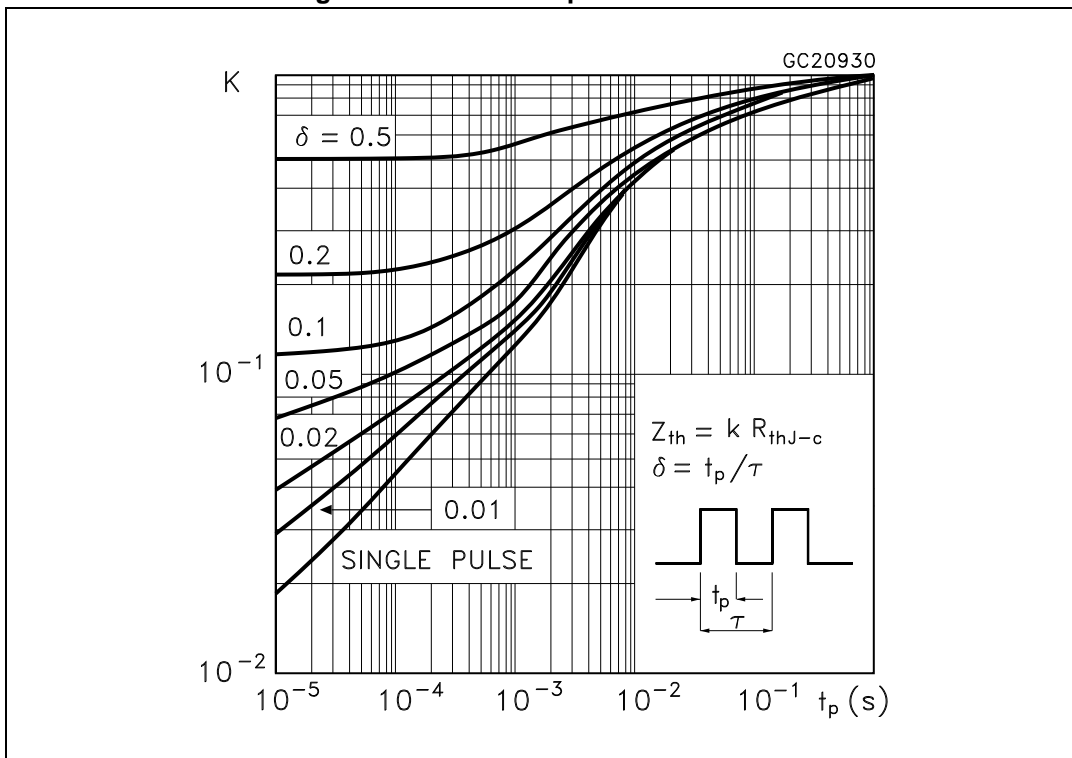


Figure 22. Thermal impedance for diode



### 3 Test circuits

Figure 23. Test circuit for inductive load switching



Figure 24. Test circuit for capacitive load switching

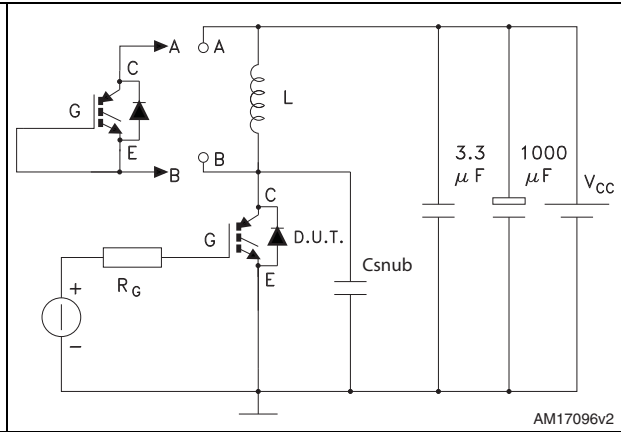
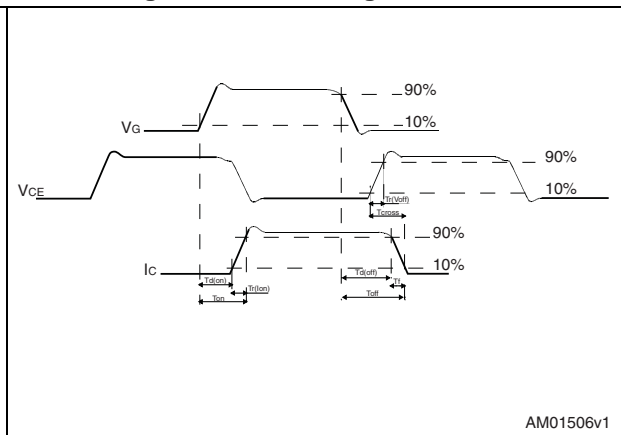


Figure 25. Gate charge test circuit



Figure 26. Switching waveform



# 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

Figure 27. TO-247 drawing

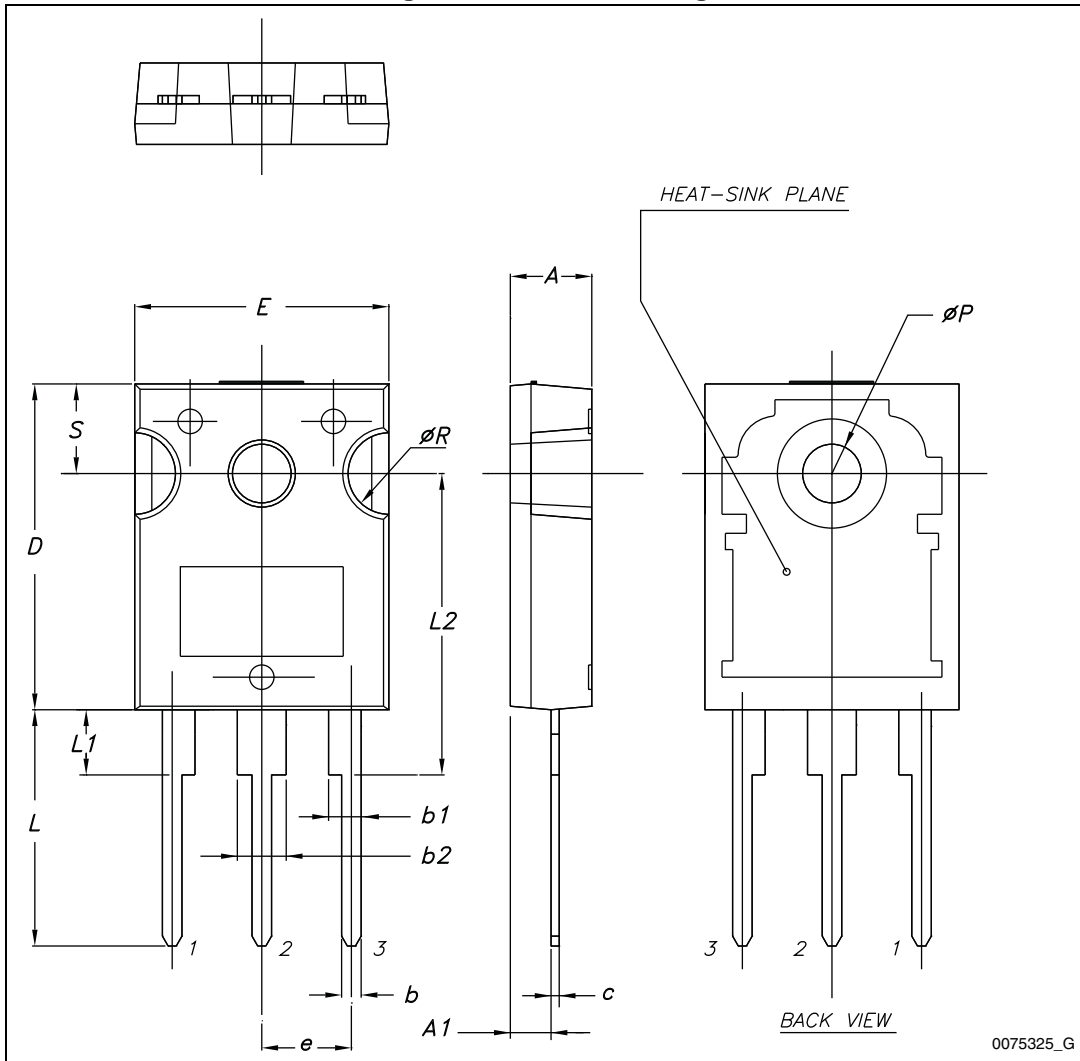
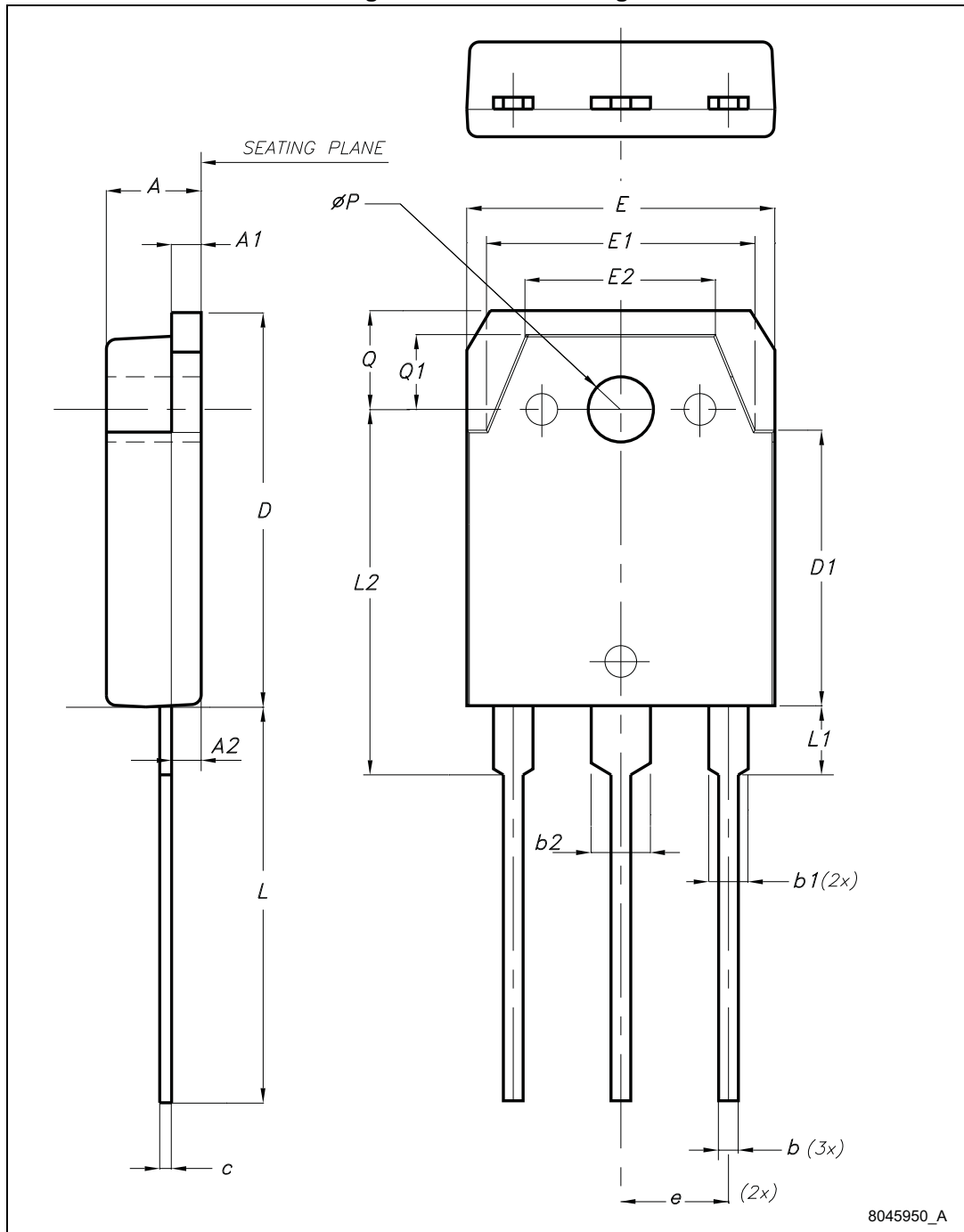


Table 8. TO-247 mechanical data

| Dim. | mm.   |       |       |
|------|-------|-------|-------|
|      | Min.  | Typ.  | Max.  |
| A    | 4.85  |       | 5.15  |
| A1   | 2.20  |       | 2.60  |
| b    | 1.0   |       | 1.40  |
| b1   | 2.0   |       | 2.40  |
| b2   | 3.0   |       | 3.40  |
| c    | 0.40  |       | 0.80  |
| D    | 19.85 |       | 20.15 |
| E    | 15.45 |       | 15.75 |
| e    | 5.30  | 5.45  | 5.60  |
| L    | 14.20 |       | 14.80 |
| L1   | 3.70  |       | 4.30  |
| L2   |       | 18.50 |       |
| ØP   | 3.55  |       | 3.65  |
| ØR   | 4.50  |       | 5.50  |
| S    | 5.30  | 5.50  | 5.70  |

Figure 28. TO-3P drawing



8045950\_A

Table 9. TO-3P mechanical data

| Dim. | mm    |       |       |
|------|-------|-------|-------|
|      | Min.  | Typ.  | Max.  |
| A    | 4.60  |       | 5     |
| A1   | 1.45  | 1.50  | 1.65  |
| A2   | 1.20  | 1.40  | 1.60  |
| b    | 0.80  | 1     | 1.20  |
| b1   | 1.80  |       | 2.20  |
| b2   | 2.80  |       | 3.20  |
| c    | 0.55  | 0.60  | 0.75  |
| D    | 19.70 | 19.90 | 20.10 |
| D1   |       | 13.90 |       |
| E    | 15.40 |       | 15.80 |
| E1   |       | 13.60 |       |
| E2   |       | 9.60  |       |
| e    | 5.15  | 5.45  | 5.75  |
| L    | 19.50 | 20    | 20.50 |
| L1   |       | 3.50  |       |
| L2   | 18.20 | 18.40 | 18.60 |
| øP   | 3.10  |       | 3.30  |
| Q    |       | 5     |       |
| Q1   |       | 3.80  |       |

## 5 Revision history

Table 10. Document revision history

| Date        | Revision | Changes  |
|-------------|----------|--|
| 13-Jan-2014 | 1        | Initial release.   |
| 03-Feb-2014 | 2        | Added $V_{CE(sat)}$ max value in <a href="#">Table 5: Dynamic characteristics</a> .<br>Minor text changes. |



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- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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